VS-UFB230FA60

Vishay Semiconductors

Insulated Ultrafast Rectifier Module, 230 A



SOT-227

PRIMARY CHARACTERISTICS						
V _R	600 V					
$I_{F(AV)}$ per module at $T_C = 88 \ ^{\circ}C$	230 A					
t _{rr}	43 ns					
Туре	Modules - diode FRED Pt [®]					
Package	SOT-227					

FEATURES

- Two fully independent diodes
- · Fully insulated package
- RoHS • Ultrafast, soft reverse recovery, with high COMPLIANT operation junction temperature (T_1 max. = 175 °C)
- Low forward voltage drop
- Optimized for power conversion: welding and industrial SMPS applications
- · Easy to use and parallel
- Industry standard outline
- UL approved file E78996
- · Designed and qualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

The VS-UFB230FA60 insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The diodes structure, and its life time control, provide an ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Cathode to anode voltage	V _R		600	V			
Continuous forward current per diode	١ _F	T _C = 85 °C	141	٨			
Single pulse forward current per diode	I _{FSM}	T _C = 25 °C	1400	A			
Maximum power dissipation per module	PD	T _C = 85 °C	416	W			
RMS isolation voltage	VISOL	Any terminal to case, t = 1 min	2500	V			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			







ELECTRICAL SPECIFICATIONS PER DIODE ($T_J = 25 \text{ °C}$ unless otherwise specified)								
PARAMETER	SYMBOL	BOL TEST CONDITIONS		TYP.	MAX.	UNITS		
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	600	-	-			
		I _F = 100 A	-	1.46	1.78			
	N	I _F = 100 A, T _J = 125 °C	-	1.23	1.52	V		
Forward voltage	V _{FM}	I _F = 200 A	-	1.70	2.05			
		I _F = 200 A, T _J = 125 °C	-	1.50	1.78			
		V _R = V _R rated	-	0.1	50	μA		
Reverse leakage current	I _{RM}	$T_J = 175 \text{ °C}, V_R = V_R \text{ rated}$	-	0.30	2	mA		
Junction capacitance	CT	V _R = 600 V	-	77	-	pF		

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t$	= 200 A/µs, V _R = 30 V	-	43	-			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	83	-	ns		
		T _J = 125 °C		-	182	-			
		T _J = 25 °C	I _F = 50 A dI _F /dt = 200 A/µs	-	7	-	А		
Peak recovery current	IRRM	T _J = 125 °C	$V_{\rm B} = 200 \text{ V}$	-	18	-	~		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	290	-	nC		
		T _J = 125 °C		-	1595	-			

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Junction to case, single leg conducting	Р		-	-	0.43		
Junction to case, both leg conducting	R _{thJC}		-	-	0.215	°C/W	
Case to heatsink	R _{thCS}	Flat, greased surface	-	0.05	-		
Weight			-	30	-	g	
Mounting torque		Torque to terminal	-	-	1.1 (9.7)	Nm (lbf.in)	
Mounting torque		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)	
Case style			SOT-227				



VS-UFB230FA60

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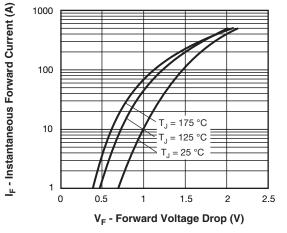


Fig. 1 - Typical Forward Voltage Drop Characteristics

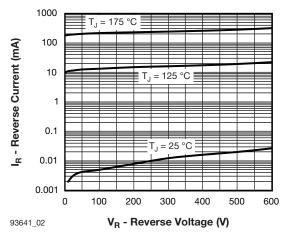


Fig. 2 - Typical Values of Reverse Current vs.Reverse Voltage

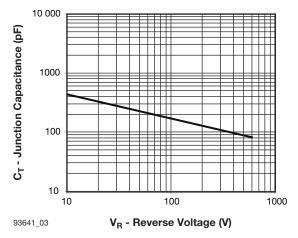
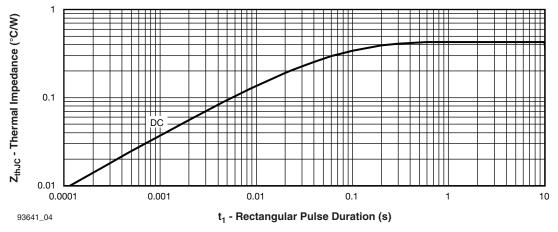


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

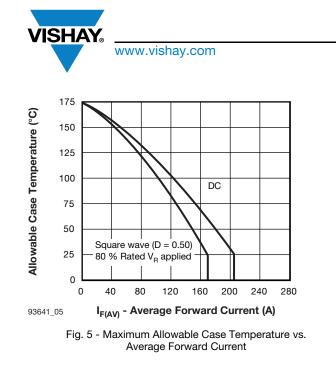


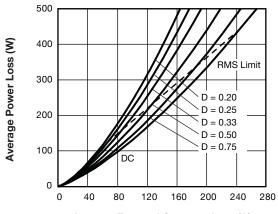


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93641_06 Average Forward Current - I_{F(AV)} (A)

Fig. 6 - Forward Power Loss Characteristics

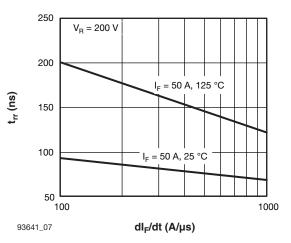
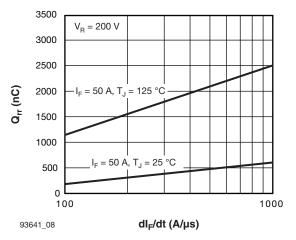
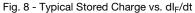


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt





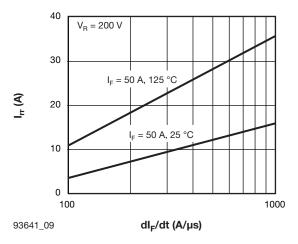


Fig. 9 - Typical I_{rr} Diode vs. $dI_{\mbox{\scriptsize F}}/dt$

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ at \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ at \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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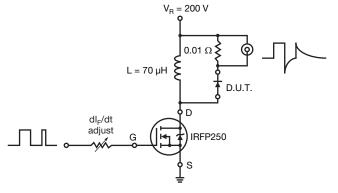
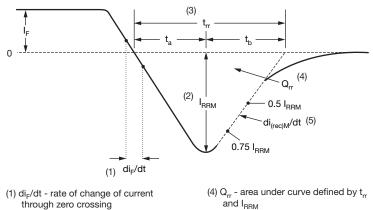
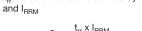


Fig. 10 - Reverse Recovery Parameter Test Circuit



- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.



$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

- (5) di_{(rec)M}/dt peak rate of change of current during t_b portion of t_{rr}
- Fig. 11 Reverse Recovery Waveform and Definitions





ORDERING INFORMATION TABLE

Device code

е	vs-	UF	В	230	F	Α	60		
	1	2	3	4	5	6	(7)		
	 Vishay Semiconductors product Ultrafast rectifier 								
	3 -	· Ultr	Ultrafast Pt diffused						
	4 -	- Cur	Current rating (230 = 230 A)						
	5 -	Circ	Circuit configuration (two separate diodes, parallel pin-ou						
	6 -	· Pac	Package indicator (SOT-227 standard insulated base)						

7 - Voltage rating (60 = 600 V)

CIRCUIT CONFIGURATION						
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
Two separate diodes, parallel pin-out	F	Lead Assignment				

LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95423</u>						
Packaging information	www.vishay.com/doc?95425					



SOT-227 Generation 2

DIMENSIONS in millimeters (inches)



Note

• Controlling dimension: millimeter



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